



STB160N75F3

STP160N75F3 - STW160N75F3

N-channel 75V - 3.5mΩ - 120A - TO-220 - TO-247 - D²PAK
MDmesh™ low voltage Power MOSFET

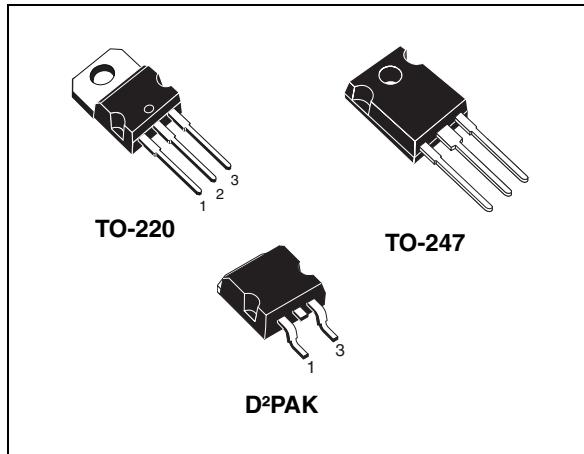
TARGET SPECIFICATION

General features

| Type | V _{DSS} | R _{DS(on)} | I _D |
|-------------|------------------|---------------------|---------------------|
| STB160N75F3 | 75V | 4.2mΩ | 120A ⁽¹⁾ |
| STP160N75F3 | 75V | 4.5mΩ | 120A ⁽¹⁾ |
| STW160N75F3 | 75V | 4.5mΩ | 120A ⁽¹⁾ |

1. Current limited by package

- Ultra low on-resistance
- 100% Avalanche tested



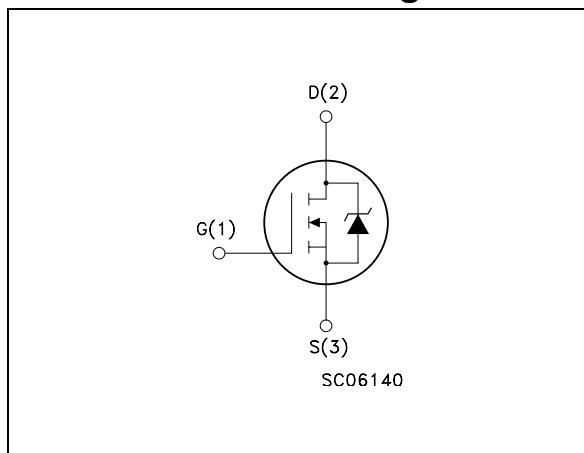
Description

This N-channel enhancement mode Power MOSFET is the latest refinement of STMicroelectronics unique "Single Feature Size™" strip-based process with less critical alignment steps and therefore a remarkable manufacturing reproducibility. The resulting transistor shows extremely high packing density for low on-resistance, rugged avalanche characteristics and low gate charge.

Applications

- Switching application

Internal schematic diagram



Order codes

| Part number | Marking | Package | Packaging |
|-------------|----------|--------------------|-------------|
| STB160N75F3 | 160N75F3 | D ² PAK | Tape & reel |
| STP160N75F3 | 160N75F3 | TO-220 | Tube |
| STW160N75F3 | 160N75F3 | TO-247 | Tube |

Contents

| | | |
|---|-----------------------------------|----|
| 1 | Electrical ratings | 3 |
| 2 | Electrical characteristics | 4 |
| 3 | Test circuit | 6 |
| 4 | Package mechanical data | 7 |
| 5 | Packaging mechanical data | 11 |
| 6 | Revision history | 12 |

1 Electrical ratings

Table 1. Absolute maximum ratings

| Symbol | Parameter | Value | Unit |
|--------------------|---|------------|---------------------|
| V_{DS} | Drain-source voltage ($V_{GS} = 0$) | 75 | V |
| V_{GS} | Gate-source voltage | ± 20 | V |
| $I_D^{(1)}$ | Drain current (continuous) at $T_C = 25^\circ\text{C}$ | 120 | A |
| $I_D^{(1)}$ | Drain current (continuous) at $T_C = 100^\circ\text{C}$ | 96 | A |
| $I_{DM}^{(2)}$ | Drain current (pulsed) | 480 | A |
| $P_{TOT}^{(3)}$ | Total dissipation at $T_C = 25^\circ\text{C}$ | 315 | W |
| | Derating factor | 2.1 | W/ $^\circ\text{C}$ |
| dv/dt | Peak diode recovery voltage slope | Tbd | V/ns |
| E_{AS} | Single pulse avalanche energy | Tbd | mJ |
| T_j T_{stg} | Operating junction temperature Storage temperature | -55 to 175 | $^\circ\text{C}$ |

1. Current limited by package
2. Pulse width limited by safe operating area
3. Rated according to Rthj-case

Table 2. Thermal resistance

| Symbol | Parameter | Value | Unit |
|-----------|--|-------|---------------------------|
| Rthj-case | Thermal resistance junction-case max | 0.48 | $^\circ\text{C}/\text{W}$ |
| Rthj-amb | Thermal resistance junction-ambient max | 62.5 | $^\circ\text{C}/\text{W}$ |
| T_I | Maximum lead temperature for soldering purpose | 300 | $^\circ\text{C}$ |

2 Electrical characteristics

($T_{CASE}=25^\circ\text{C}$ unless otherwise specified)

Table 3. On/off states

| Symbol | Parameter | Test conditions | | Min. | Typ. | Max | Unit |
|---------------------|--|--|--------------------|------|------------|------------|--------------------------------------|
| $V_{(BR)DSS}$ | Drain-source breakdown voltage | $I_D = 250\mu\text{A}, V_{GS} = 0$ | | 75 | | | V |
| I_{DSS} | Zero gate voltage drain current ($V_{GS} = 0$) | $V_{DS} = \text{Max rating}, V_{DS} = \text{Max rating, } @ 125^\circ\text{C}$ | | | | 10 100 | μA μA |
| I_{GSS} | Gate body leakage current ($V_{DS} = 0$) | $V_{GS} = \pm 20\text{V}$ | | | | ± 200 | nA |
| $V_{GS(\text{th})}$ | Gate threshold voltage | $V_{DS} = V_{GS}, I_D = 250\mu\text{A}$ | | 2 | | 4 | V |
| $R_{DS(\text{on})}$ | Static drain-source on resistance | $V_{GS} = 10\text{V}, I_D = 60\text{A}$ | D ² PAK | | 3.5 3.2 | 4.5 4.2 | $\text{m}\Omega$ $\text{m}\Omega$ |

Table 4. Dynamic

| Symbol | Parameter | Test conditions | Min | Typ | Max | Unit |
|-------------------------------------|---|---|-----|--------------------|-----|----------------|
| $g_{fs}^{(1)}$ | Forward transconductance | $V_{DS} = 15\text{V}, I_D = 4.5\text{A}$ $I_D = 10\text{A}$ | | Tbd | | S |
| C_{iss} C_{oss} C_{rss} | Input capacitance Output capacitance Reverse transfer capacitance | $V_{DS} = 25\text{V}, f = 1 \text{ MHz}, V_{GS} = 0$ | | 7000 1100 32 | | pF pF pF |
| Q_g Q_{gs} Q_{gd} | Total gate charge Gate-source charge Gate-drain charge | $V_{DD} = 44\text{V}, I_D = 60\text{A}$ $V_{GS} = 10\text{V}$ <i>(see Figure 2)</i> | | 110 Tbd Tbd | | nC nC nC |

1. Pulsed: pulse duration = 300µs, duty cycle 1.5%

Table 5. Switching times

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|--------------|---------------------|--|------|------|------|------|
| $t_{d(on)}$ | Turn-on delay time | $V_{DD}=35\text{ V}$, $I_D=60\text{A}$, $R_G=4.7\Omega$, $V_{GS}=10\text{V}$, (see Figure 4) | Tbd | ns | ns | ns |
| t_r | Rise time | | | | | |
| $t_{d(off)}$ | Turn-off delay time | | | | | |
| t_f | Fall time | | | | | |

Table 6. Source drain diode

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|-----------------|-------------------------------|--|----------------|---------------|---------------|---------------|
| I_{SD} | Source-drain current | | | | 120 | A |
| $I_{SDM}^{(1)}$ | Source-drain current (pulsed) | | | | 480 | A |
| $V_{SD}^{(2)}$ | Forward on voltage | $I_{SD}=120\text{A}$, $V_{GS}=0$ | | | 1.5 | V |
| t_{rr} | Reverse recovery time | $I_{SD}=120\text{A}$, $dI/dt = 100\text{A}/\mu\text{s}$, $V_{DD}=30\text{ V}$, $T_j=150^\circ\text{C}$ (see Figure 3) | 75 195 5 | ns nC A | ns nC A | ns nC A |
| Q_{rr} | Reverse recovery charge | | | | | |
| I_{RRM} | Reverse recovery current | | | | | |

1. Pulse with limited by safe operating area
2. Pulsed: pulse duration = 300μs, duty cycle 1.5%

3 Test circuit

Figure 1. Switching times test circuit for resistive load

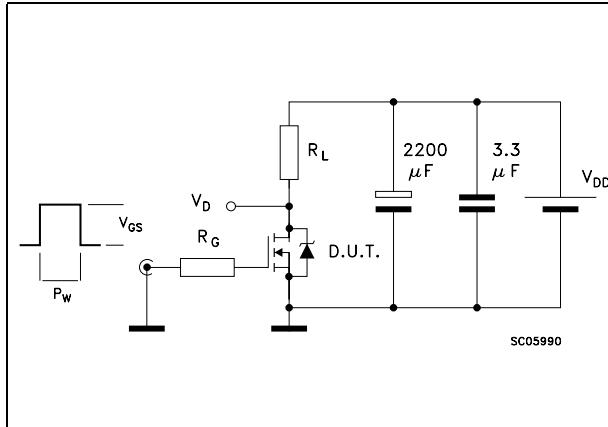


Figure 2. Gate charge test circuit

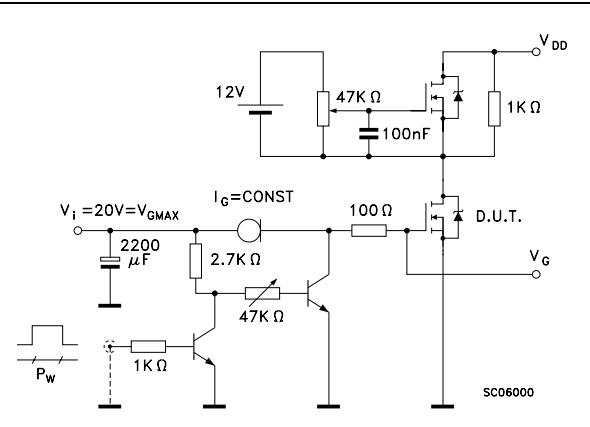


Figure 3. Test circuit for inductive load switching and diode recovery times

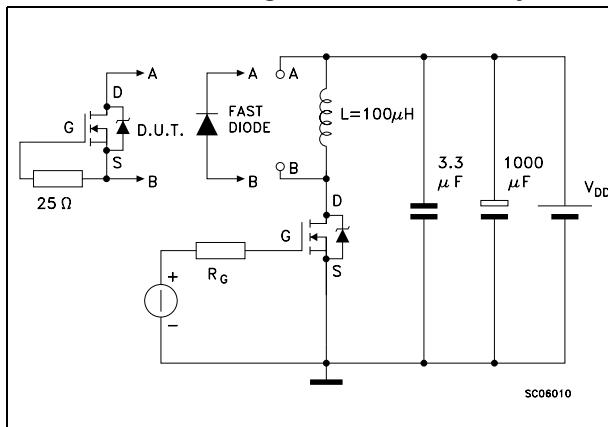


Figure 4. Unclamped inductive load test circuit

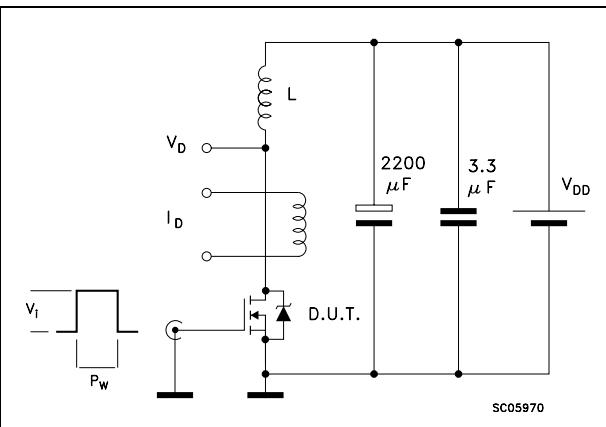


Figure 5. Unclamped inductive waveform

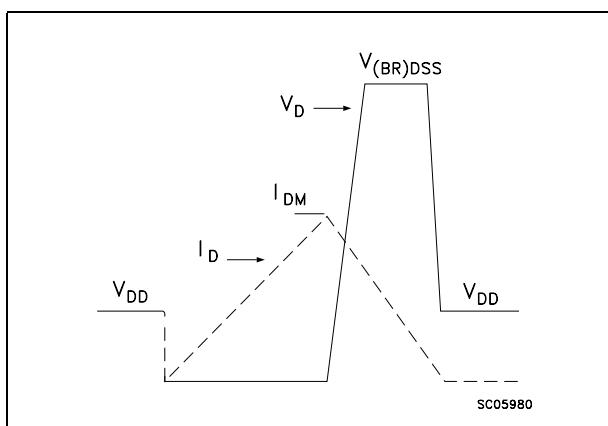
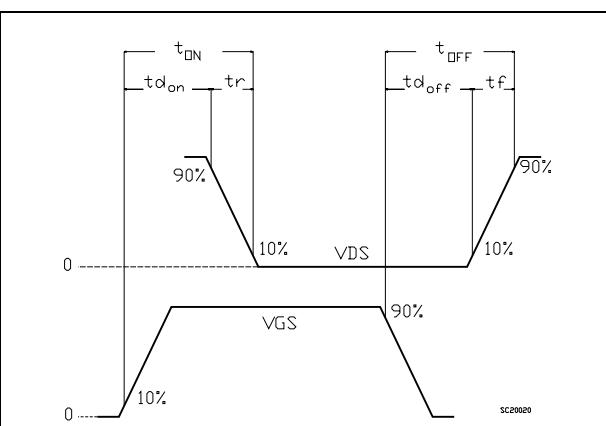


Figure 6. Switching time waveform

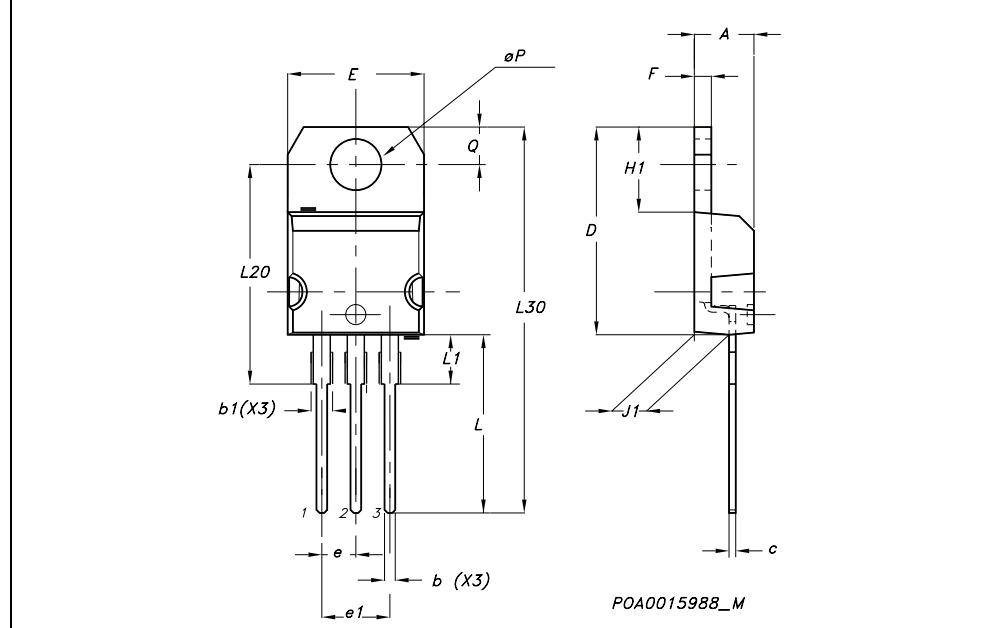


4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

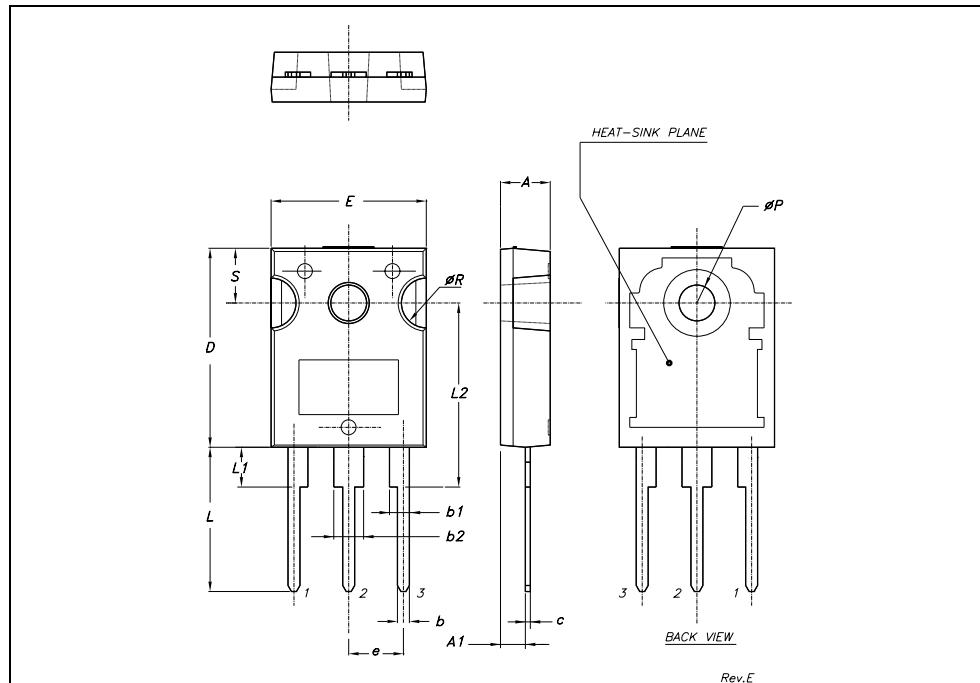
TO-220 MECHANICAL DATA

| DIM. | mm. | | | inch | | |
|------|-------|-------|-------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 4.40 | | 4.60 | 0.173 | | 0.181 |
| b | 0.61 | | 0.88 | 0.024 | | 0.034 |
| b1 | 1.15 | | 1.70 | 0.045 | | 0.066 |
| c | 0.49 | | 0.70 | 0.019 | | 0.027 |
| D | 15.25 | | 15.75 | 0.60 | | 0.620 |
| E | 10 | | 10.40 | 0.393 | | 0.409 |
| e | 2.40 | | 2.70 | 0.094 | | 0.106 |
| e1 | 4.95 | | 5.15 | 0.194 | | 0.202 |
| F | 1.23 | | 1.32 | 0.048 | | 0.052 |
| H1 | 6.20 | | 6.60 | 0.244 | | 0.256 |
| J1 | 2.40 | | 2.72 | 0.094 | | 0.107 |
| L | 13 | | 14 | 0.511 | | 0.551 |
| L1 | 3.50 | | 3.93 | 0.137 | | 0.154 |
| L20 | | 16.40 | | | 0.645 | |
| L30 | | 28.90 | | | 1.137 | |
| øP | 3.75 | | 3.85 | 0.147 | | 0.151 |
| Q | 2.65 | | 2.95 | 0.104 | | 0.116 |



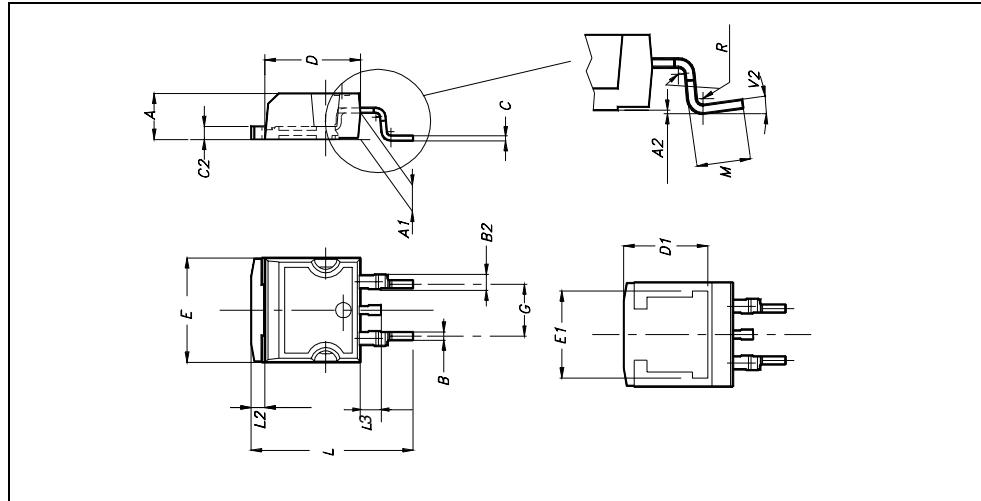
TO-247 MECHANICAL DATA

| DIM. | mm. | | | inch | | |
|----------|-------|-------|-------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 4.85 | | 5.15 | 0.19 | | 0.20 |
| A1 | 2.20 | | 2.60 | 0.086 | | 0.102 |
| b | 1.0 | | 1.40 | 0.039 | | 0.055 |
| b1 | 2.0 | | 2.40 | 0.079 | | 0.094 |
| b2 | 3.0 | | 3.40 | 0.118 | | 0.134 |
| c | 0.40 | | 0.80 | 0.015 | | 0.03 |
| D | 19.85 | | 20.15 | 0.781 | | 0.793 |
| E | 15.45 | | 15.75 | 0.608 | | 0.620 |
| e | | 5.45 | | | 0.214 | |
| L | 14.20 | | 14.80 | 0.560 | | 0.582 |
| L1 | 3.70 | | 4.30 | 0.14 | | 0.17 |
| L2 | | 18.50 | | | 0.728 | |
| ϕP | 3.55 | | 3.65 | 0.140 | | 0.143 |
| ϕR | 4.50 | | 5.50 | 0.177 | | 0.216 |
| S | | 5.50 | | | 0.216 | |



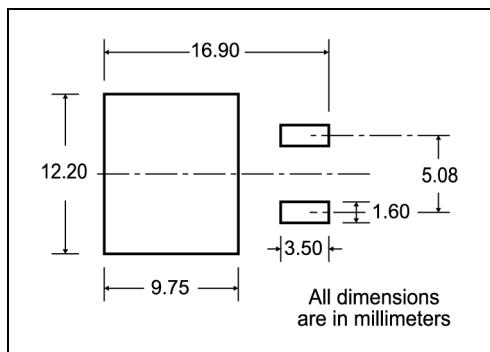
D²PAK MECHANICAL DATA

| DIM. | mm. | | | inch | | |
|------|------|------|-------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 4.4 | | 4.6 | 0.173 | | 0.181 |
| A1 | 2.49 | | 2.69 | 0.098 | | 0.106 |
| A2 | 0.03 | | 0.23 | 0.001 | | 0.009 |
| B | 0.7 | | 0.93 | 0.027 | | 0.036 |
| B2 | 1.14 | | 1.7 | 0.044 | | 0.067 |
| C | 0.45 | | 0.6 | 0.017 | | 0.023 |
| C2 | 1.23 | | 1.36 | 0.048 | | 0.053 |
| D | 8.95 | | 9.35 | 0.352 | | 0.368 |
| D1 | | 8 | | | 0.315 | |
| E | 10 | | 10.4 | 0.393 | | |
| E1 | | 8.5 | | | 0.334 | |
| G | 4.88 | | 5.28 | 0.192 | | 0.208 |
| L | 15 | | 15.85 | 0.590 | | 0.625 |
| L2 | 1.27 | | 1.4 | 0.050 | | 0.055 |
| L3 | 1.4 | | 1.75 | 0.055 | | 0.068 |
| M | 2.4 | | 3.2 | 0.094 | | 0.126 |
| R | | 0.4 | | | 0.015 | |
| V2 | 0° | | 4° | | | |



5 Packaging mechanical data

D²PAK FOOTPRINT



TAPE AND REEL SHIPMENT

| REEL MECHANICAL DATA | | | | |
|----------------------|------|----------|-------|--------|
| DIM. | mm | | inch | |
| | MIN. | MAX. | MIN. | MAX. |
| A | | | 330 | 12.992 |
| B | 1.5 | | 0.059 | |
| C | 12.8 | 13.2 | 0.504 | 0.520 |
| D | 20.2 | | 0795 | |
| G | 24.4 | 26.4 | 0.960 | 1.039 |
| N | 100 | | 3.937 | |
| T | | 30.4 | | 1.197 |
| BASE QTY | | BULK QTY | | |
| 1000 | | 1000 | | |

TAPE MECHANICAL DATA

| DIM. | mm | | inch | |
|------|------|------|--------|--------|
| | MIN. | MAX. | MIN. | MAX. |
| A0 | 10.5 | 10.7 | 0.413 | 0.421 |
| B0 | 15.7 | 15.9 | 0.618 | 0.626 |
| D | 1.5 | 1.6 | 0.059 | 0.063 |
| D1 | 1.59 | 1.61 | 0.062 | 0.063 |
| E | 1.65 | 1.85 | 0.065 | 0.073 |
| F | 11.4 | 11.6 | 0.449 | 0.456 |
| K0 | 4.8 | 5.0 | 0.189 | 0.197 |
| P0 | 3.9 | 4.1 | 0.153 | 0.161 |
| P1 | 11.9 | 12.1 | 0.468 | 0.476 |
| P2 | 1.9 | 2.1 | 0.075 | 0.082 |
| R | 50 | | 1.574 | |
| T | 0.25 | 0.35 | 0.0098 | 0.0137 |
| W | 23.7 | 24.3 | 0.933 | 0.956 |

* on sales type

6 Revision history

Table 7. Revision history

| Date | Revision | Changes |
|-------------|----------|---------------|
| 07-Feb-2007 | 1 | First release |

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